









**CD74ACT157** 

SCHS340C - MARCH 2003 - REVISED AUGUST 2024

# CD74ACT157 Quadruple 2-Line to 1-Line Data Selector/Multiplexer

### 1 Features

- Inputs are TTL-voltage compatible
- Speed of bipolar F, AS, and S, with significantly reduced power consumption
- Balanced propagation delays
- ±24mA output drive current
  - Fanout to 15 F devices
- SCR-latchup-resistant CMOS process and circuit
- Exceeds 2kV ESD protection per MIL-STD-883, method 3015

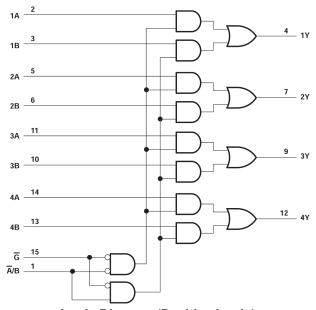
# 2 Description

This quadruple 2-line to 1-line data selector/ multiplexer is designed for 4.5V to 5.5V V<sub>CC</sub> operation.

#### **Package Information**

	•		
PART NUMBER	BER PACKAGE <sup>(1)</sup> PACKAGE SIZE <sup>(1)</sup>		BODY SIZE(3)
	D (SOIC, 16)	9.90 mm × 6mm	9.90 mm × 3.90 mm
CD74ACT157	N (PDIP, 16)	19.31 mm × 9.4mm	19.31 mm × 6.35 mm
	PW (TSSOP, 16)	5.00 mm × 6.4mm	5.00 mm × 4.40 mm

- For more information, see Section 10. (1)
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



**Logic Diagram (Positive Logic)** 



# **Table of Contents**

1 Features	1 6.2 Functional Block Diagram	8
2 Description	<u> </u>	
3 Pin Configuration and Functions	3 7 Application and Implementation	9
4 Specifications		
4.1 Absolute Maximum Ratings		9
4.2 ESD Ratings		
4.3 Recommended Operating Conditions		
4.4 Thermal Information		
4.5 Electrical Characteristics	•	
4.6 Switching Characteristics		
4.7 Operating Characteristics		10
5 Parameter Measurement Information		
6 Detailed Description	· · · · · · · · · · · · · · · · · · ·	
6.1 Overview		10

# 3 Pin Configuration and Functions

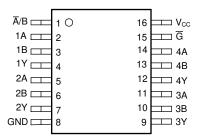


Figure 3-1. N, D, or PW Package; 16-Pin PDIP, SOIC, or TSSOP (Top View)

**Table 3-1. Pin Functions** 

P	PIN TYPE(1)		DESCRIPTION
NAME	NO.	I TPE\''	DESCRIPTION
Ā/B	1	I	Address select
1A	2	I	Channel 1, data input A
1B	3	I	Channel 1, data input B
1Y	4	0	Channel 1, data output
2A	5	I	Channel 2, data input A
2B	6	I	Channel 2, data input B
2Y	7	0	Channel 2, data output
GND	8	G	Ground
3Y	9	0	Channel 3, data output
3B	10	I	Channel 3, data input B
3A	11	I	Channel 3, data input A
4Y	12	0	Channel 4, data output
4B	13	I	Channel 4, data input B
4A	14	I	Channel 4, data input A
G	15	I	Output strobe, active low
V <sub>CC</sub>	16	Р	Positive supply
Thermal pad <sup>(2)</sup>		_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.

<sup>(1)</sup> Signal Types: I = Input, O = Output, I/O = Input or Output, P = Power, G = Ground.

<sup>(2)</sup> WBQB package only.



# 4 Specifications

# 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	6	V
I <sub>IK</sub> (2)	Input clamp current	$(V_I < 0 \text{ V or } V_I > V_{CC})$		±20	mA
I <sub>OK</sub> (2)	Output clamp current	$(V_O < 0 \text{ V or } V_O > V_{CC})$		±50	mA
Io	Continuous output current	$(V_O > 0 \text{ V or } V_O < V_{CC})$		±50	mA
	Continuous current through V <sub>CC</sub> or GND	·		±100	mA
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 4.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

# 4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		T <sub>A</sub> = 2	T <sub>A</sub> = 25°C		-55°C to 125°C		85°C	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5.5	4.5	5.5	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8		0.8	V
VI	Input voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
Vo	Output voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		-24		-24		-24	mA
I <sub>OL</sub>	Low-level output current		24		24		24	mA
Δt/Δν	Input transition rise or fall rate		10		10		10	ns/V

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### 4.4 Thermal Information

THERMAL METRIC(1)					
		D (SOIC)	N (PDIP)	PW (TSSOP)	UNIT
			16		
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	119.9	67	145.7	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Product Folder Links: CD74ACT157

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	METER TEST CONDITIONS V <sub>CC</sub>		TEST CONDITIONS Voc		5 °C	-55°C to 125°C		-40°C to 85°C		UNIT
PARAMETER			MIN	MAX	MIN	MAX	MIN	MAX	UNII	
		I <sub>OH</sub> = -50 μA	4.5 V	4.4		4.4		4.4		
V	$V_{I} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -24 mA	4.5 V	3.94		3.7		3.8		V
V <sub>OH</sub>	VI - VIH OI VIL	$I_{OH} = -50 \text{ mA}^{(1)}$	5.5 V			3.85				
		$I_{OH} = -75 \text{ mA}^{(1)}$	5.5 V					3.85		
	$V_{I} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 50 μA	4.5 V		0.1		0.1		0.1	V
V		I <sub>OL</sub> = 24 mA	4.5 V		0.36		0.5		0.44	
V <sub>OL</sub>		I <sub>OL</sub> = 50 mA <sup>(1)</sup>	5.5 V				1.65			
		I <sub>OL</sub> = 75 mA <sup>(1)</sup>	5.5 V						1.65	
I <sub>1</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND		5.5 V		±0.1		±1		±1	μA
I <sub>cc</sub>	$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	5.5 V		8		160		80	μA
ΔI <sub>CC</sub> (2)	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V	•	4.5 V to 5.5 V		2.4		3		2.8	mA
C <sub>i</sub>					10		10		10	pF

<sup>(1)</sup> Test one output at a time, not exceeding 1-second duration. Measurement is made by forcing indicated current and measuring voltage to minimize power dissipation. Test verifies a minimum 50-Ω transmission-line drive capability at 85°C and 75-Ω transmission-line drive capability at 125°C.

(2) Additional quiescent supply current per input pin, TTL inputs high, 1 unit load

**Table 4-1. Act Input Loading Table** 

INPUT	UNIT LOAD
A or B	0.37
G	0.83
Ā/B	1.33

# 4.6 Switching Characteristics

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V,  $C_L$  = 50 pF (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	-55°C to	125°C	-40°C to 8	5°C	UNIT
PARAMETER	PROW (INPUT)	10 (001701)	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	A or B	A or B Any Y	2.4	9.5	2.5	8.6	ns
t <sub>PHL</sub>			2.4	9.5	2.5	8.6	
t <sub>PLH</sub>	Ā/B	Any V	3.6	14.5	3.8	13.2	ne
t <sub>PHL</sub>	A/B	Any Y	3.6	14.5	3.8	13.2	ns
t <sub>PLH</sub>	G	Any V	3.4	13.5	3.6	12.3	20
t <sub>PHL</sub>	J	Any Y	3.4	13.5	3.6	12.3	ns

# 4.7 Operating Characteristics

 $V_{CC}$  = 5 V,  $T_A$  = 25°C

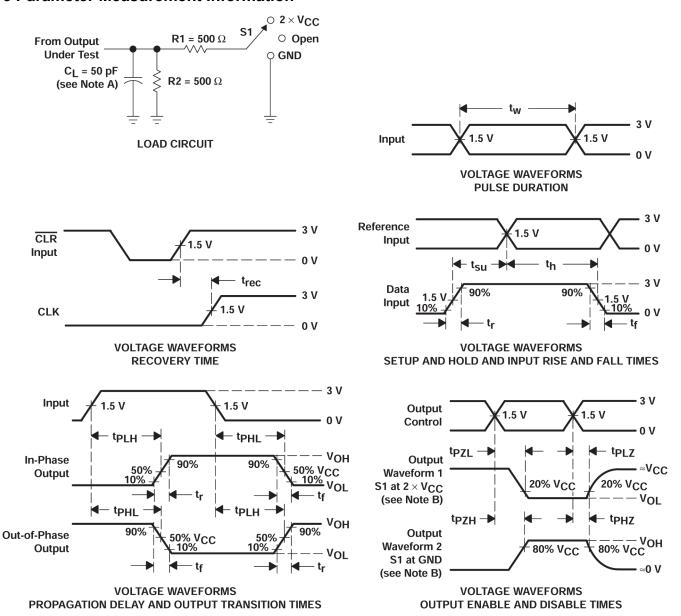
	PARAMETER	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	156	pF

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## **5 Parameter Measurement Information**



- C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r$  = 3 ns,  $t_f$  = 3 ns. Phase relationships between waveforms are arbitrary.
- D. For clock inputs,  $f_{\text{max}}$  is measured with the input duty cycle at 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
- G.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- H. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- I. All parameters and waveforms are not applicable to all devices.

Figure 5-1. Load Circuit and Voltage Waveforms

TEST	<b>S1</b>
t <sub>PLH</sub> /t <sub>PHL</sub>	Open

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TEST	<b>S1</b>
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 × V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

# **6 Detailed Description**

# **6.1 Overview**

The CD74ACT157 features a common strobe ( $\overline{G}$ ) input. When the strobe is high, all outputs are low. When the strobe is low, a 4-bit word is selected from one of two sources and is routed to the four outputs. The device provides true data.

# 6.2 Functional Block Diagram

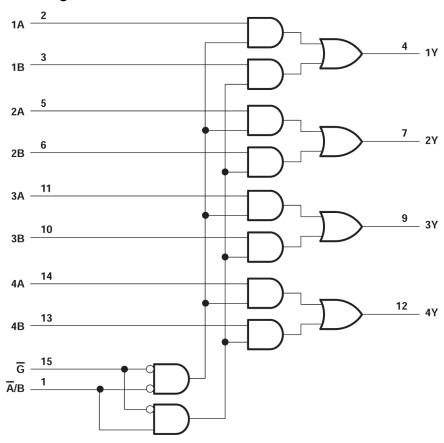


Figure 6-1. Logic Diagram (Positive Logic)

### **6.3 Device Functional Modes**

**Table 6-1. Function Table** 

	OUTPUT			
G	A/B	Α	В	Υ
Н	X	Х	Х	L
L	L	L	Х	L
L	L	Н	Х	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

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# 7 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

# 7.1 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 $\mu$ f is recommended; if there are multiple  $V_{CC}$  pins, then 0.01 $\mu$ f or 0.022  $\mu$ f is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 $\mu$ f and a 1 $\mu$ f are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

### 7.2 Layout

## 7.2.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in Layout Diagram are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

#### 7.2.2 Layout Example

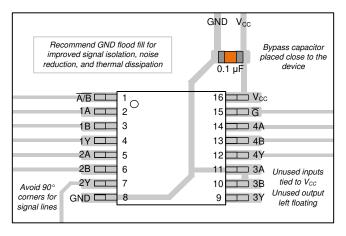


Figure 7-1. Example Layout for the CD74ACT157



# 8 Device and Documentation Support

# 8.1 Documentation Support (Analog)

#### 8.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

#### Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
CD74ACT157	Click here	Click here	Click here	Click here	Click here

## 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 8.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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### 8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

# 8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision B (June 2003) to Revision C (August 2024)

Page

- Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

# 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: CD74ACT157

www.ti.com 30-Jul-2024

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
CD74ACT157E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT157E	Samples
CD74ACT157M	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	ACT157M	
CD74ACT157M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT157M	Samples
CD74ACT157PW	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HM157	
CD74ACT157PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HM157	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE MATERIALS INFORMATION**

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# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

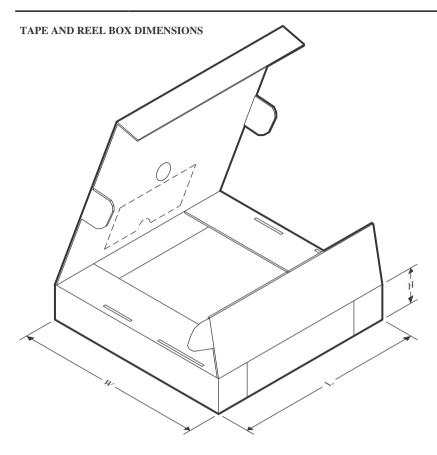
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74ACT157PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74ACT157PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 6-Nov-2024



## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74ACT157PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74ACT157PWR	TSSOP	PW	16	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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# **TUBE**



### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74ACT157E	N	PDIP	16	25	506	13.97	11230	4.32
CD74ACT157E	N	PDIP	16	25	506	13.97	11230	4.32

# D (R-PDS0-G16)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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